CSD23280F3 –12-V P-Channel FemtoFET™ MOSFET

1 Features

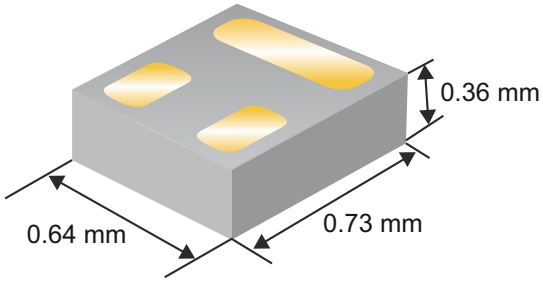
- Low On-Resistance
- Ultra-Low Q_g and Q_{gd}
- High-operating drain current
- Ultra-small footprint
  - 0.73 mm × 0.64 mm
- Ultra-low profile
  - 0.36-mm max height
- Integrated ESD protection diode
  - Rated > 4-kV HBM
  - Rated > 2-kV CDM
- Lead and halogen free
- RoHS compliant

2 Applications

- Optimized for load switch applications
- Optimized for general purpose switching applications
- Battery applications
- Handheld and mobile applications

3 Description

This –12-V, 97-mΩ, P-Channel FemtoFET™ MOSFET is designed and optimized to minimize the footprint in many handheld and mobile applications. This technology is capable of replacing standard small signal MOSFETs while providing a substantial reduction in footprint size.



Typical Part Dimensions

Product Summary

T_A = 25°C		TYPICAL VALUE		UNIT
V_{DS}	Drain-to-Source Voltage	–12		V
Q_g	Gate Charge Total (4.5 V)	0.95		nC
Q_{gd}	Gate Charge Gate-to-Drain	0.068		nC
$R_{DS(on)}$	Drain-to-Source On-Resistance	V_{GS} = –1.5 V	230	mΩ
		V_{GS} = –1.8 V	180	
		V_{GS} = –2.5 V	129	
		V_{GS} = –4.5 V	97	
$V_{GS(th)}$	Threshold Voltage	–0.65		V

Device Information(1)

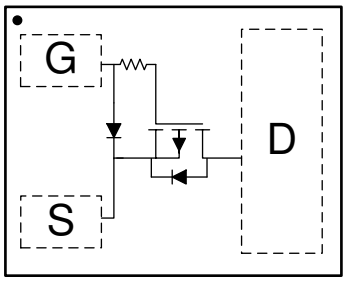
DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD23280F3	3000	7-Inch Reel	Femto 0.73-mm × 0.64-mm Land Grid Array (LGA)	Tape and Reel
CSD23280F3T	250			

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

T_A = 25°C		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	–12	V
V_{GS}	Gate-to-Source Voltage	–6	V
I_D	Continuous Drain Current(1)	2.9	A
	Continuous Drain Current(2)	1.8	
I_{DM}	Pulsed Drain Current(1) (3)	11.4	A
P_D	Power Dissipation(1)	1.4	W
	Power Dissipation(2)	0.5	
$V_{(ESD)}$	Human-Body Model (HBM)	4000	V
	Charged-Device Model (CDM)	2000	
T_J, T_{stg}	Operating Junction, Storage Temperature	–55 to 150	°C

(1) Typical $R_{\theta JA}$ = 90°C/W on 1-in^2 (6.45-cm^2), 2-oz (0.071-mm) thick Cu pad on a 0.06-in (1.52-mm) thick FR4 PCB
(2) Typical $R_{\theta JA}$ = 255°C/W on min Cu board
(3) Pulse duration ≤ 100 µs, duty cycle ≤ 1%.



Top View

Table of Contents

4 Revision History

Changes from Revision A (August 2017) to Revision B (February 2022) **Page**

- Changed ultra-low profile bullet from 0.35 mm to 0.36 mm in height.... 1
- Added max Cu currents and power dissipation limits 1
- Added min Cu footnote 1
- Updated ultra-low profile image height from 0.35 mm to 0.36 mm.... 1
- Changed ultra-low profile image height from 0.35 mm to 0.36 mm.... 8
- Added FemtoFET Surface Mount Guide note.... 9

Changes from Revision * (April 2016) to Revision A (August 2017) **Page**

- Added the *Section 6.1* section in *Section 6* 7
- Updated the *Section 7.3* 9

5 Specifications

5.1 Electrical Characteristics

T_A = 25°C (unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
BV_{DSS}	Drain-to-source voltage	V_{GS} = 0 V, I_{DS} = –250 µA	–12			V
I_{DSS}	Drain-to-source leakage current	V_{GS} = 0 V, V_{DS} = –9.6 V			–50	nA
I_{GSS}	Gate-to-source leakage current	V_{DS} = 0 V, V_{GS} = –5 V			–25	nA
$V_{GS(th)}$	Gate-to-source threshold voltage	V_{DS} = V_{GS}, I_{DS} = –250 µA	–0.40	–0.65	–0.95	V
$R_{DS(on)}$	Drain-to-source on-resistance	V_{GS} = –1.5 V, I_{DS} = –0.1 A		230	399	mΩ
		V_{GS} = –1.8 V, I_{DS} = –0.4 A		180	250	
		V_{GS} = –2.5 V, I_{DS} = –0.4 A		129	165	
		V_{GS} = –4.5 V, I_{DS} = –0.4 A		97	116	
g_{fs}	Transconductance	V_{DS} = –1.2 V, I_{DS} = –0.4 A		3		S
DYNAMIC CHARACTERISTICS						
C_{iss}	Input capacitance	V_{GS} = 0 V, V_{DS} = –6 V, f = 1 MHz		180	234	pF
C_{oss}	Output capacitance			73	95	pF
C_{rss}	Reverse transfer Capacitance			8.5	11.1	pF
R_G	Series gate resistance			9		Ω
Q_g	Gate charge total (4.5 V)	V_{DS} = –6 V, I_{DS} = –0.4 A		0.95	1.23	nC
Q_{gd}	Gate charge gate-to-drain			0.068		nC
Q_{gs}	Gate charge gate-to-source			0.30		nC
$Q_{g(th)}$	Gate charge at V_{th}			0.15		nC
Q_{oss}	Output charge	V_{DS} = –6 V, V_{GS} = 0 V		1.07		nC
$t_{d(on)}$	Turnon delay time	V_{DS} = –6 V, V_{GS} = –4.5 V, I_{DS} = –0.4 A, R_G = 0 Ω		8		ns
t_r	Rise time			4		ns
$t_{d(off)}$	Turnoff delay time			21		ns
t_f	Fall time			8		ns
DIODE CHARACTERISTICS						
V_{SD}	Diode forward voltage	I_{SD} = –0.4 A, V_{GS} = 0 V		–0.73	–1.0	V

5.2 Thermal Information

T_A = 25°C (unless otherwise stated)

THERMAL METRIC		TYPICAL VALUES	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance(1)	90	°C/W
	Junction-to-ambient thermal resistance(2)	255	

(1) Device mounted on FR4 material with 1-in^2 (6.45-cm^2), 2-oz. (0.071-mm) thick Cu.
(2) Device mounted on FR4 material with minimum Cu mounting area.

5.3 Typical MOSFET Characteristics

T_A = 25°C (unless otherwise stated)

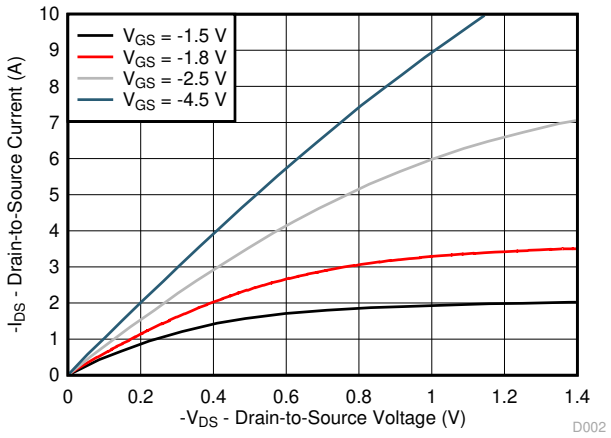
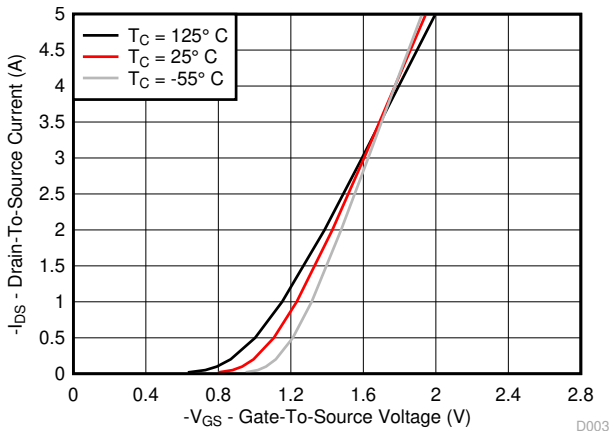


Figure 5-1. Saturation Characteristics



V_{DS} = –5 V

Figure 5-2. Transfer Characteristics

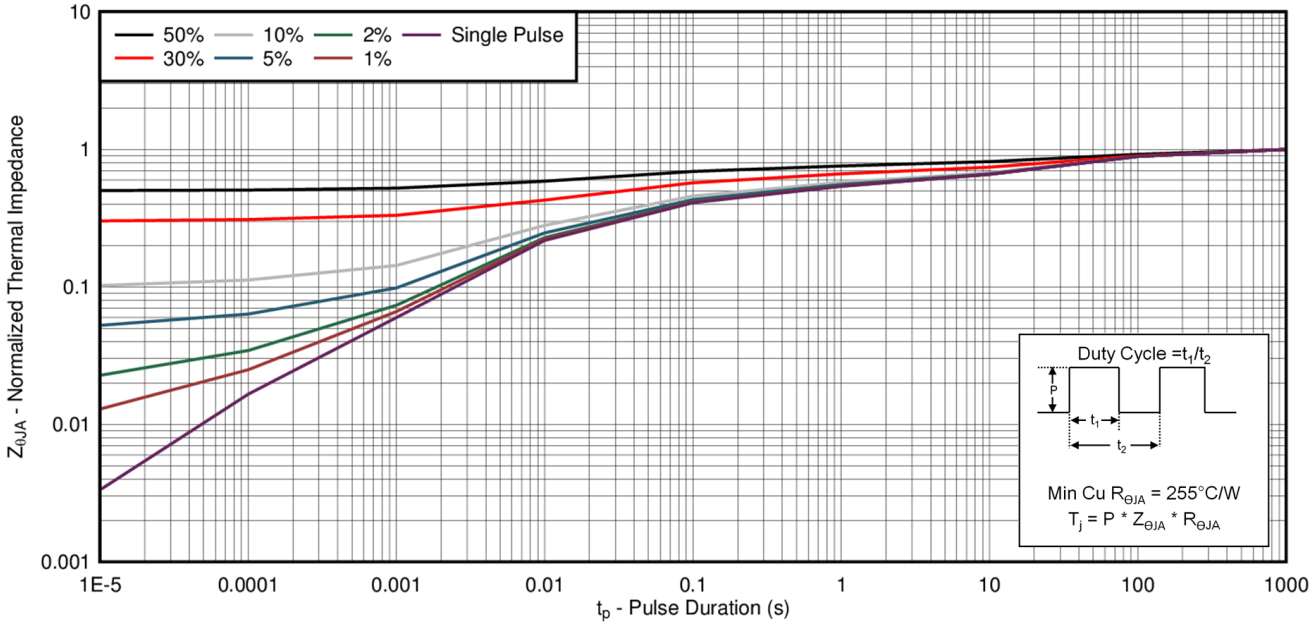
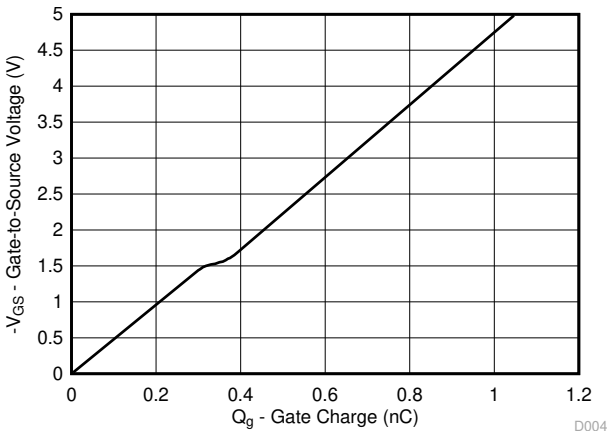


Figure 5-3. Transient Thermal Impedance



V_{DS} = –6 V I_D = –0.4 A

Figure 5-4. Gate Charge

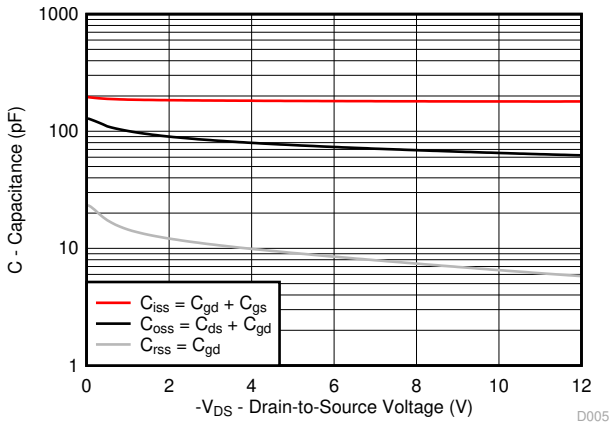
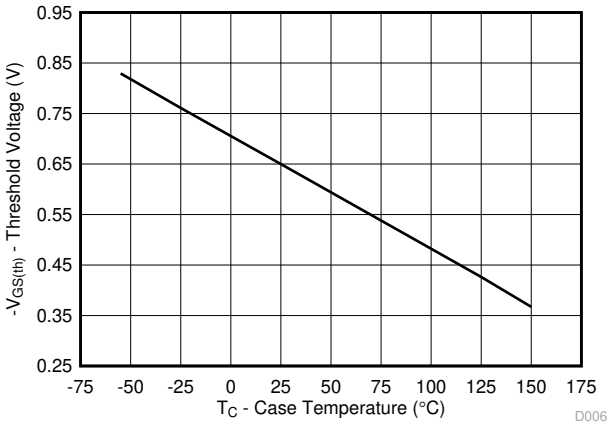


Figure 5-5. Capacitance



I_D = –250 µA

Figure 5-6. Threshold Voltage vs Temperature

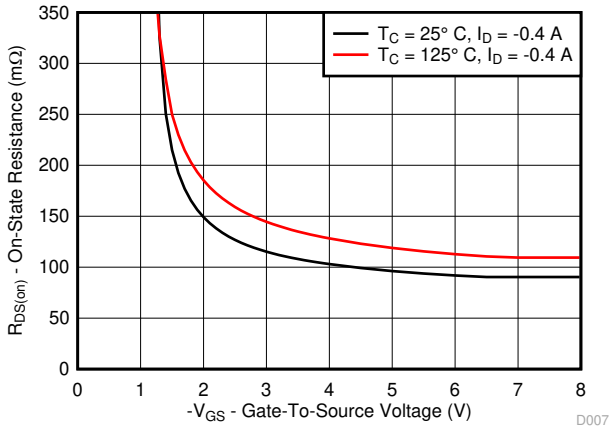
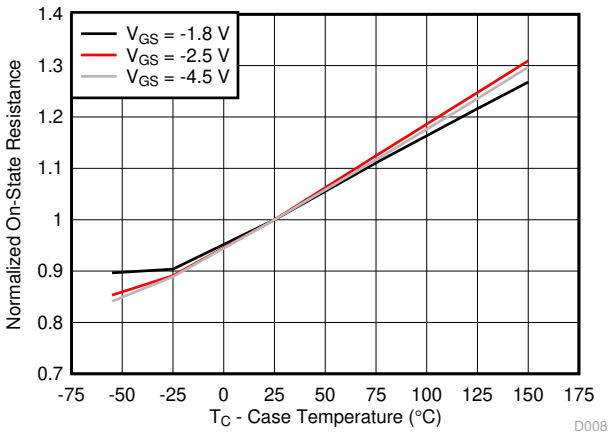


Figure 5-7. On-State Resistance vs Gate-to-Source Voltage



V_{GS} = –4.5 V I_D = –0.4 A

Figure 5-8. Normalized On-State Resistance vs Temperature

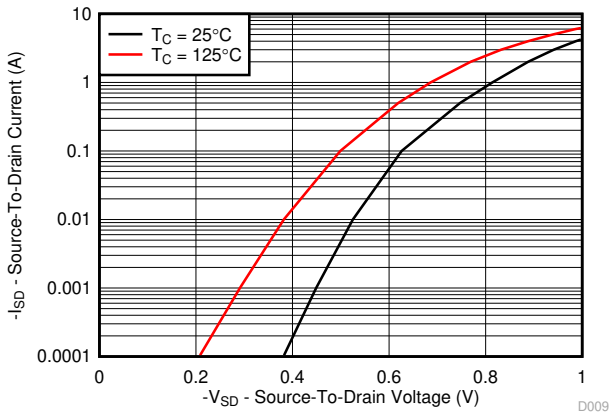
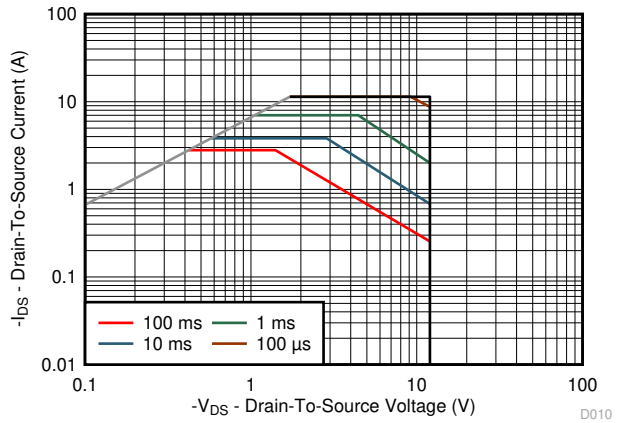


Figure 5-9. Typical Diode Forward Voltage



Single pulse, max $R_{\theta JA}$ = 255°C/W

Figure 5-10. Maximum Safe Operating Area

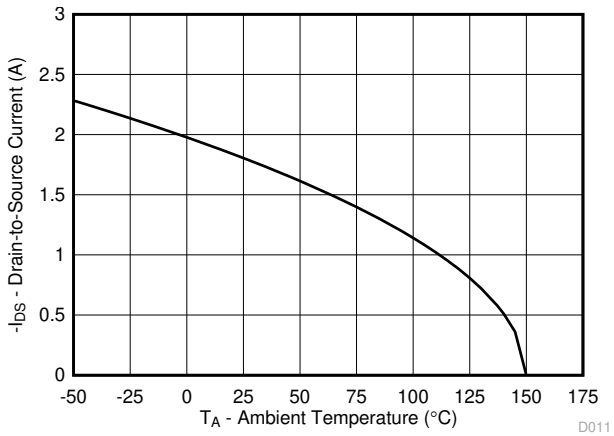


Figure 5-11. Maximum Drain Current vs Temperature

6 Device and Documentation Support

6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

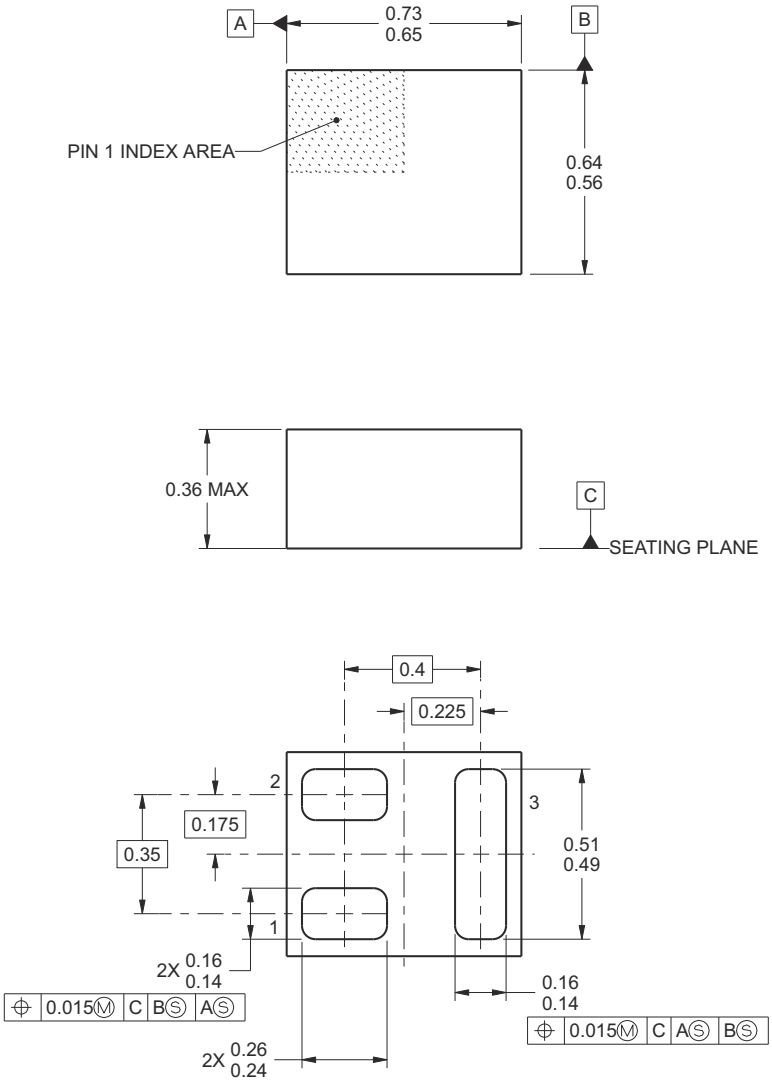
6.2 Trademarks

FemtoFET™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Mechanical Dimensions

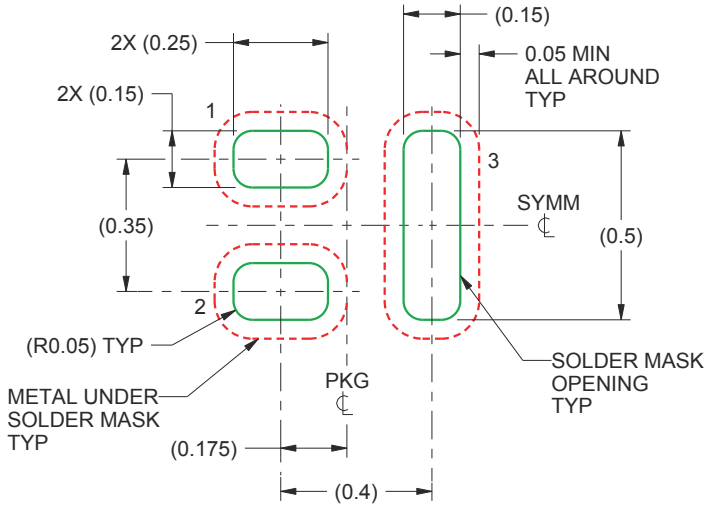


A. All linear dimensions are in millimeters (dimensions and tolerancing per AME T14.5M-1994).
B. This drawing is subject to change without notice.
C. This package is a lead-free solder land design.

Table 7-1. Pin Configuration

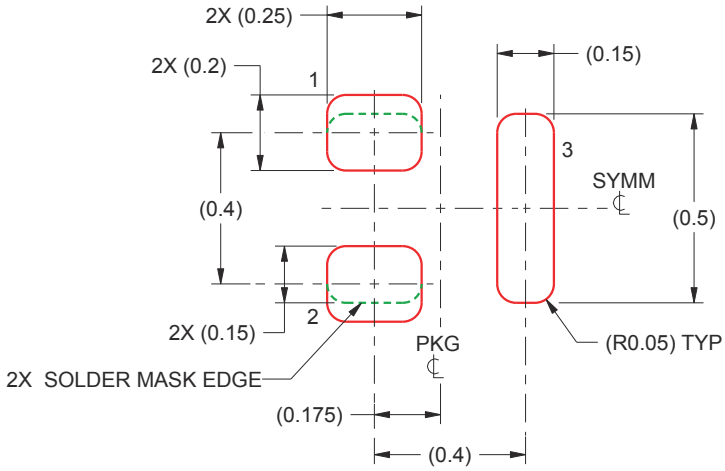
POSITION	DESIGNATION
Pin 1	Gate
Pin 2	Source
Pin 3	Drain

7.2 Recommended Minimum PCB Layout



A. All dimensions are in millimeters.
B. For more information, see *FemtoFET Surface Mount Guide* (SLRA003D).

7.3 Recommended Stencil Pattern



A. All dimensions are in millimeters.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CSD23280F3	Active	Production	PICOSTAR (YJM) | 3	3000 | LARGE T&R	Yes	NIAU	Level-1-260C-UNLIM	-55 to 150	5
CSD23280F3.B	Active	Production	PICOSTAR (YJM) | 3	3000 | LARGE T&R	Yes	NIAU	Level-1-260C-UNLIM	-55 to 150	5
CSD23280F3T	Active	Production	PICOSTAR (YJM) | 3	250 | SMALL T&R	Yes	NIAU	Level-1-260C-UNLIM	-55 to 150	5
CSD23280F3T.B	Active	Production	PICOSTAR (YJM) | 3	250 | SMALL T&R	Yes	NIAU	Level-1-260C-UNLIM	-55 to 150	5

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

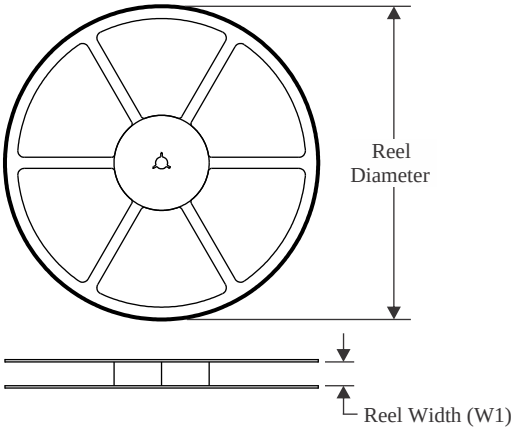
(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

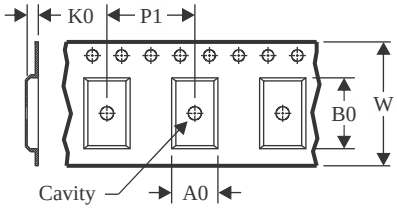
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

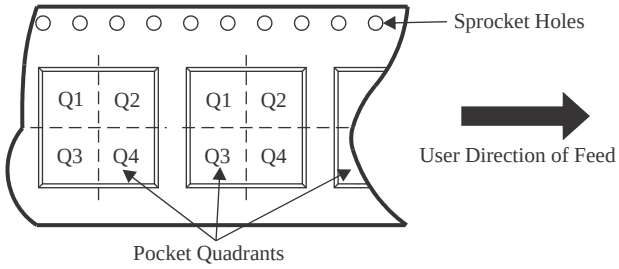


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

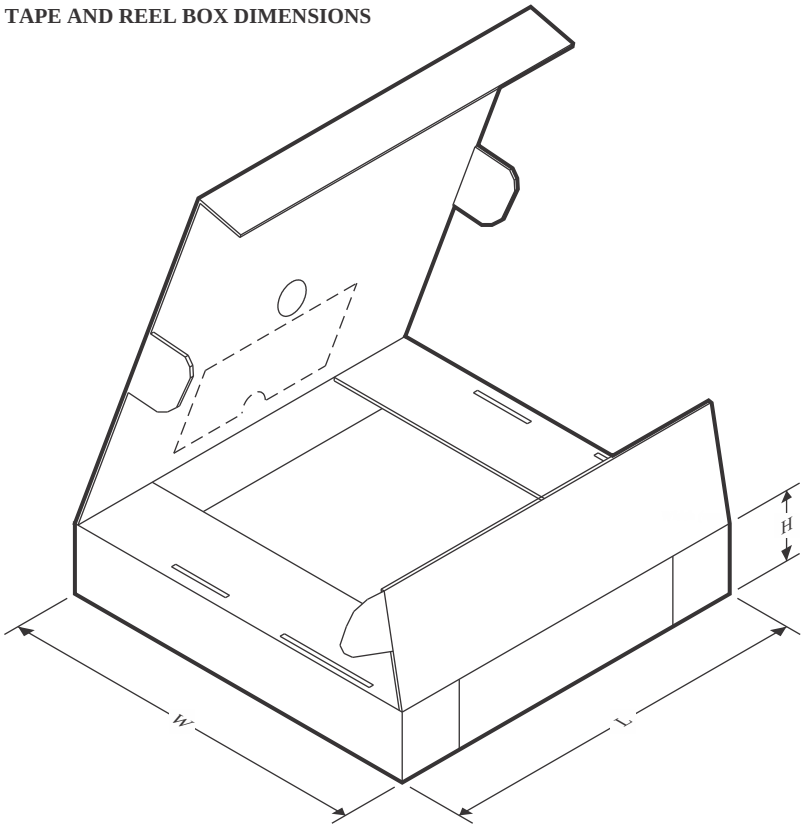
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD23280F3	PICOSTAR	YJM	3	3000	180.0	8.4	1.94	0.79	0.44	4.0	8.0	Q2
CSD23280F3T	PICOSTAR	YJM	3	250	180.0	8.4	1.94	0.79	0.44	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD23280F3	PICOSTAR	YJM	3	3000	182.0	182.0	20.0
CSD23280F3T	PICOSTAR	YJM	3	250	182.0	182.0	20.0

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES “AS IS” AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI’s products are provided subject to TI’s Terms of Sale, TI’s General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI’s provision of these resources does not expand or otherwise alter TI’s applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Last updated 10/2025